### INTEGRATED CIRCUITS

# DATA SHEET



# 74LVT2245

3.3V Octal transceiver with  $30\Omega$  termination resistors (3-State)

Product specification Supersedes data of 1996 Mar 11 IC23 Data Handbook





## 3.3V Octal transceiver with 30 $\Omega$ termination resistors (3-State)

#### 74LVT2245

#### **FEATURES**

- 30Ω output termination resistors
- Octal bidirectional bus interface
- 3-State buffers
- Output capability: +12mA/-12mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

#### **DESCRIPTION**

The LVT2245 is a high-performance BiCMOS product designed for V<sub>CC</sub> operation at 3.3V.

This device is an octal transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable (OE) input for easy cascading and a Direction (DIR) input for direction control.

The 74LVT2245 is designed with  $30\Omega$  series resistance in both the High and Low states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

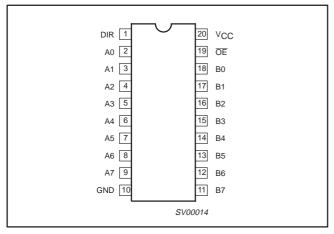
#### **QUICK REFERENCE DATA**

and 200V per Ma	xceeds 2000V per MIL STD 883 Method 301 chine Model	5		
QUICK REFER	ENCE DATA	7, 44		
SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Bn or Bn to An	$C_L = 50pF;$ $V_{GC} = 3.3V$	3.2 3.1	ns
C <sub>IN</sub>	Input capacitance DIR, OE	V <sub>I</sub> = <b>0V</b> or 3.0V	4	pF
C <sub>I/O</sub>	I/O pin capacitance	Outputs disabled; V <sub>I/O</sub> = 0V or 3.0V	10	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; V <sub>CC</sub> = 3.6V	0.13	mA

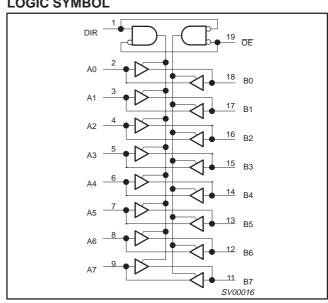
#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic SO	-40°C to +85°C	74LVT2245 D	74LVT2245 D	SOT163-1
20-Pin Plastic SSOP	–40°C to +85°C	74LVT2245 DB	74LVT2245 DB	SOT339-1
20-Pin Plastic TSSOP	-40°C to +85°C	74LVT2245 PW	7LVT2245PW DH	SOT360-1

#### **PIN CONFIGURATION**



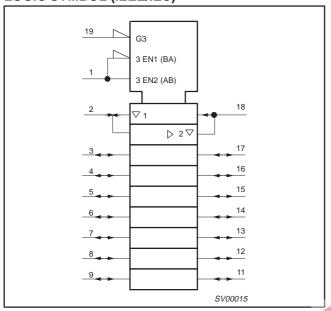
#### LOGIC SYMBOL



### 3.3V Octal transceiver with $30\Omega$ termination resistors (3-State)

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#### LOGIC SYMBOL (IEEE/IEC)



#### PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	DIR	Direction control input
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	ŌĒ	Output enable input (active-Low)
10	GND	Ground (0V)
20	V <sub>CC</sub>	Positive supply voltage

#### **FUNCTION TABLE**

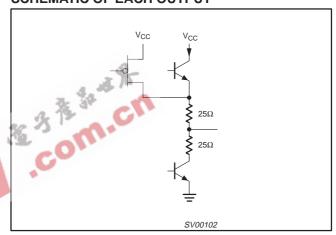
INP	UTS	INPUTS/C	OUTPUTS
<del>OE</del> n	DIR	An	Bn
L	L	An= Bn	Inputs
L	Н	Inputs	Bn =An
Н	Х	Z	Z

H = High voltage level
L = Low voltage level

X = Don't care

Z = High impedance "Off" state

#### SCHEMATIC OF EACH OUTPUT



#### **ABSOLUTE MAXIMUM RATINGS<sup>1,2</sup>**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-50	mA
VI	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or High state	-0.5 to +7.0	V
	DC system to suggest	Output in Low state	128	A
louт	DC output current	Output in High state	-64	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

#### NOTES:

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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#### RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWIBOL	FARAMETER	MIN	MAX	ONII
V <sub>CC</sub>	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
$V_{IH}$	High-level input voltage	2.0		V
$V_{IL}$	Input voltage		0.8	V
I <sub>OH</sub>	High-level output current		-12	mA
I <sub>OL</sub>	Low-level output current		12	mA
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

#### DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -40°C to +85°			C UNIT	
			4 35 10	MIN	TYP <sup>1</sup>	MAX	1
V <sub>IK</sub>	Input clamp voltage	V <sub>CC</sub> = 2.7V; I <sub>IK</sub> = -18mA	30		-0.9	-1.2	V
V <sub>OH</sub>	High-level output voltage	$V_{CC} = 3.0V; I_{OH} = -12mA$		2.0	2.2		V
V <sub>OL</sub>	Low-level output voltage	V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 12mA	444			0.8	V
		$V_{CC} = 0 \text{ or } 3.6 \text{ V}; V_{I} = 5.5 \text{ V}$	Control pins		1	10	
		$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND	Control pins		±0.1	±1	]
I <sub>I</sub>	Input leakage current	$V_{CC} = 3.6V; V_1 = 5.5V$			1	20	μΑ
		$V_{CC} = 3.6V; V_I = V_{CC}$	I/O Data pins <sup>4</sup>		0.1	1	
		$V_{CC} = 3.6V; V_{I} = 0$	]		-1	-5	1
I <sub>OFF</sub>	Output off current	$V_{CC} = 0V$ ; $V_I$ or $V_O = 0$ to 4.5V			1	±100	μА
		$V_{CC} = 3V; V_I = 0.8V$		75	150		
I <sub>HOLD</sub>	Bus Hold current A inputs <sup>6</sup>	$V_{CC} = 3V; V_I = 2.0V$		-75	-150		μΑ
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
I <sub>EX</sub>	Current into an ouptut in the High state when V <sub>O</sub> > V <sub>CC</sub>	$V_O = 5.5V; V_{CC} = 3.0V$			60	125	μА
I <sub>PU/PD</sub>	Power up/down 3-State output current <sup>3</sup>	$V_{CC} \le 1.2V$ ; $V_O = 0.5V$ to $V_{CC}$ ; $V_I = GNIOE/OE = Don't$ care	O or V <sub>CC</sub> ;		15	±100	μА
I <sub>CCH</sub>		$V_{CC} = 3.6V$ ; Outputs High, $V_I = GND$ or	V <sub>CC</sub> , I <sub>O</sub> = 0		0.13	0.19	
I <sub>CCL</sub>	Quiescent supply current	$V_{CC} = 3.6V$ ; Outputs Low, $V_I = GND$ or $V_{CC} = 0.6V$	V <sub>CC</sub> , I <sub>O =</sub> 0		3	12	mA
I <sub>CCZ</sub>	1	$V_{CC} = 3.6V$ ; Outputs Disabled; $V_I = GNE$		0.13	0.19	1	
Δl <sub>CC</sub>	Additional supply current per input pin <sup>3</sup>	$V_{CC}$ = 3V to 3.6V; One input at $V_{CC}$ -0.6° Other inputs at $V_{CC}$ or GND	V,		0.1	0.2	mA

- NOTES:
   All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.
   This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND
   This parameter is valid for any V<sub>CC</sub> between 0V and 1.2V with a transition time of up to 10msec. From V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T<sub>amb</sub> = +25°C only.
   Unused pins at V<sub>CC</sub> or GND.
   I<sub>CCZ</sub> is measured with outputs pulled up to V<sub>CC</sub> or down to GND
   This is the bus held quardities gurrent required to force the input to the appeals logic at the

- 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

# 3.3V Octal transceiver with $30\Omega$ termination resistors (3-State)

74LVT2245

#### **AC CHARACTERISTICS**

GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF;  $R_L$  = 500 $\Omega$ ;  $T_{amb}$  = -40°C to +85°C.

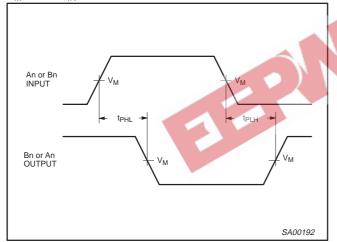
				LIMITS				
SYMBOL	PARAMETER	WAVEFORM	$V_{CC} = 3.3V + 0.3V$		V <sub>CC</sub> = 2.7V	UNIT		
			MIN	TYP	MAX	MAX		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Bn or Bn to An	1	1.0 1.0	3.2 3.1	4.6 4.5	5.3 4.9	ns	
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	2	1.1 1.5	4.5 4.3	7.0 6.5	9.1 7.6	ns	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from High and Low Level	2	2.2 2.0	3.7 3.6	5.2 5.0	5.6 5.0	ns	

#### NOTE

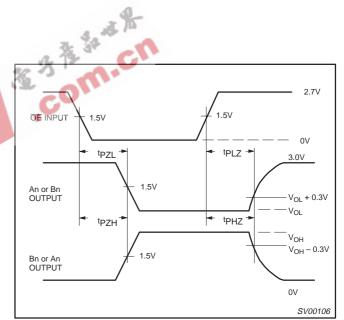
1. All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

#### **AC WAVEFORMS**

 $V_M = 1.5V$ ,  $V_{IN} = GND$  to 2.7V



Waveform 1. Input (An or Bn) to Output (Bn or An) Propagation Delays



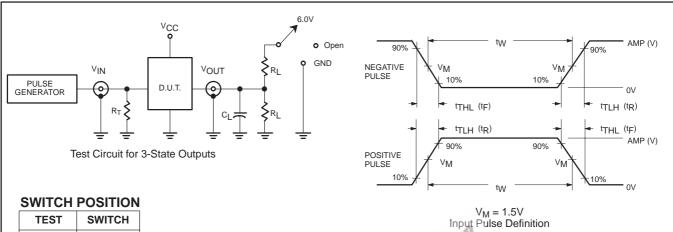
Waveform 2. 3-State Output Enable and Disable Times

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# 3.3V Octal transceiver with $30\Omega$ termination resistors (3-State)

### 74LVT2245

#### **TEST CIRCUIT AND WAVEFORMS**



#### **SWITCH POSITION**

TEST	SWITCH
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	6V
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

#### **DEFINITIONS**

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

Termination resistance should be equal to Z<sub>OUT</sub> of pulse generators.

	<u> </u>	養物	PUT PULSE R		MENTS	
F	AMILY	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>
	74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

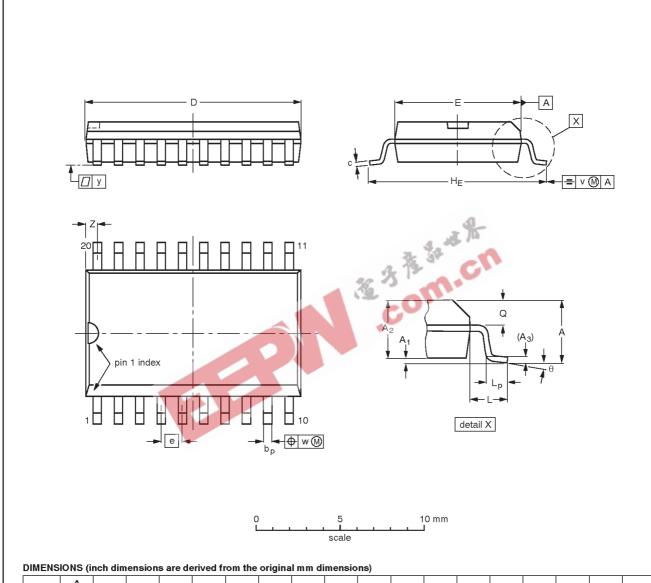
SV00092

# 3.3V Octal transceiver with $30\Omega$ termination resistors (3-State)

74LVT2245

#### SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	z <sup>(1)</sup>	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016		0.01	0.01	0.004	0.035 0.016	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013AC			<del>-92-11-17</del> 95-01-24

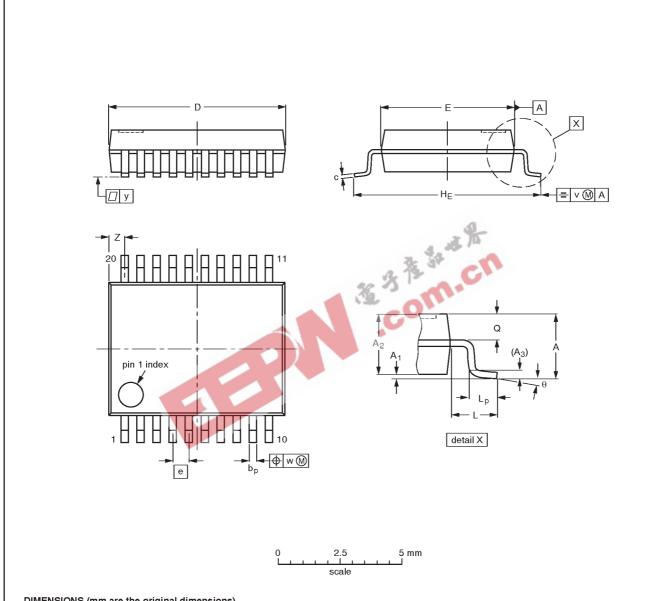
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# 3.3V Octal transceiver with $30\Omega$ termination resistors (3-State)

74LVT2245

#### SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



#### **DIMENSIONS** (mm are the original dimensions)

						-,												
UNIT	A max.	Α1	A <sub>2</sub>	А3	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

#### Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

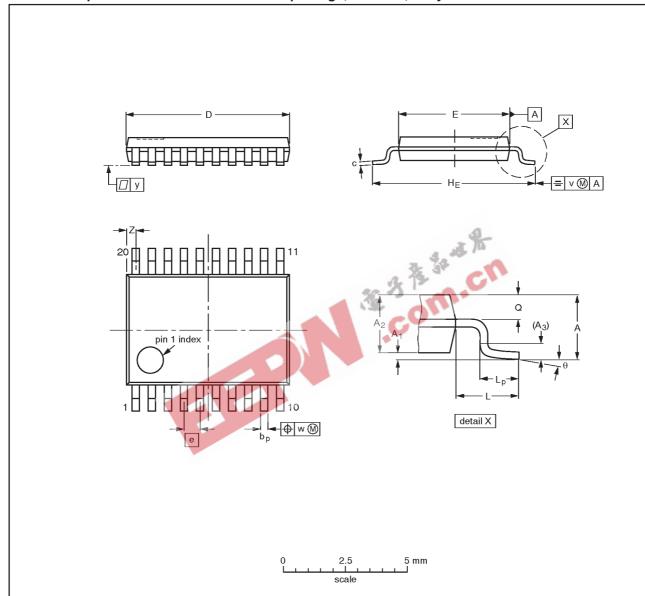
OUTLINE		EUROPEAN	ISSUE DATE				
VERSION	IEC	IEC JEDEC			PROJECTION	ISSUE DATE	
SOT339-1		MO-150AE				<del>-93-09-08</del> 95-02-04	

# 3.3V Octal transceiver with $30\Omega$ termination resistors (3-State)

74LVT2245

#### TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT360-1		MO-153AC			<del>-93-06-16</del> 95-02-04

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### 3.3V Octal transceiver with $30\Omega$ termination resistors (3-State)

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#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date.  Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

<sup>[1]</sup> Please consult the most recently issued datasheet before initiating or completing a design.

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Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability

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